

Integrated Automotive TFT-LCD Power Supply Regulator

ISL78419

The ISL78419 is an integrated power management IC (PMIC) for TFT-LCDs used in central display, rear seat entertainment and virtual dashboards. The device integrates a boost converter for generating A_{VDD} , an LDO regulator for V_{LOGIC} . V_{ON} and V_{OFF} are generated by a charge pump driven by the switch node of the boost converter. The ISL78419 also includes a V_{ON} slice circuit, reset function, and a high performance VCOM amplifier with a Digitally Controlled Potentiometer (DCP) that is used as a VCOM calibrator.

The A_{VDD} boost converter features a 1.5A/0.18 Ω boost FET with 600kHz/1200kHz switching frequency.

The integrated logic LDO includes a 350mA FET for driving the low voltage needed by external digital circuitry.

The gate pulse modulator can control the gate voltage up to 30V, and both the rate and slew delay times are selectable.

The supply monitor generates a reset signal when the system is powered down based on a user selected threshold level (programming resistor).

The ISL78419 provides a digitally controlled VCOM output using I²C interface. One VCOM amplifier is also integrated in the chip to provide a fast slewing 150mA drive (sourcing or sinking). The output of the VCOM is powered up with the voltage stored at the last programmed 8-bit (internal) EEPROM setting.

The ISL78419 is rated to operate over the temperature range of (-40°C to +105°C) and is qualified according to AEC - Q100.

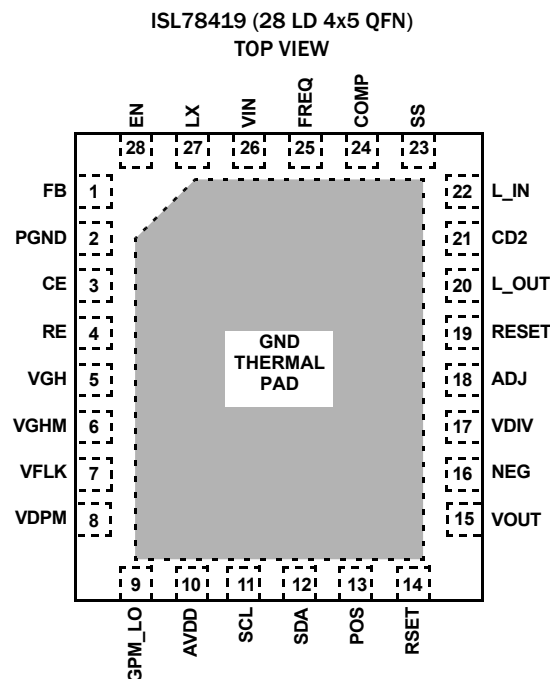
Features

- 2.5V to 5.5V input
- 1.5A, 0.18 Ω integrated boost FET
- V_{ON}/V_{OFF} supplies generated by charge pumps driven by the boost switch node
- LDO for V_{LOGIC} channel
- 600kHz/1200kHz selectable switching frequency
- Integrated gate pulse modulator
- Reset signal generated by supply monitor
- Integrated VCOM amplifier
- DCP
 - I²C serial interface, address: 0101000, MSB left
 - Wiper position stored in 8-bit nonvolatile memory and recalled on power-up
 - Endurance, 1,000 data changes per bit
- UVLO, UVP, OVP, OCP, and OTP protection
- Pb-free (RoHS compliant)
- 28 Ld 4x5 QFN
- AEC - Q100 qualified

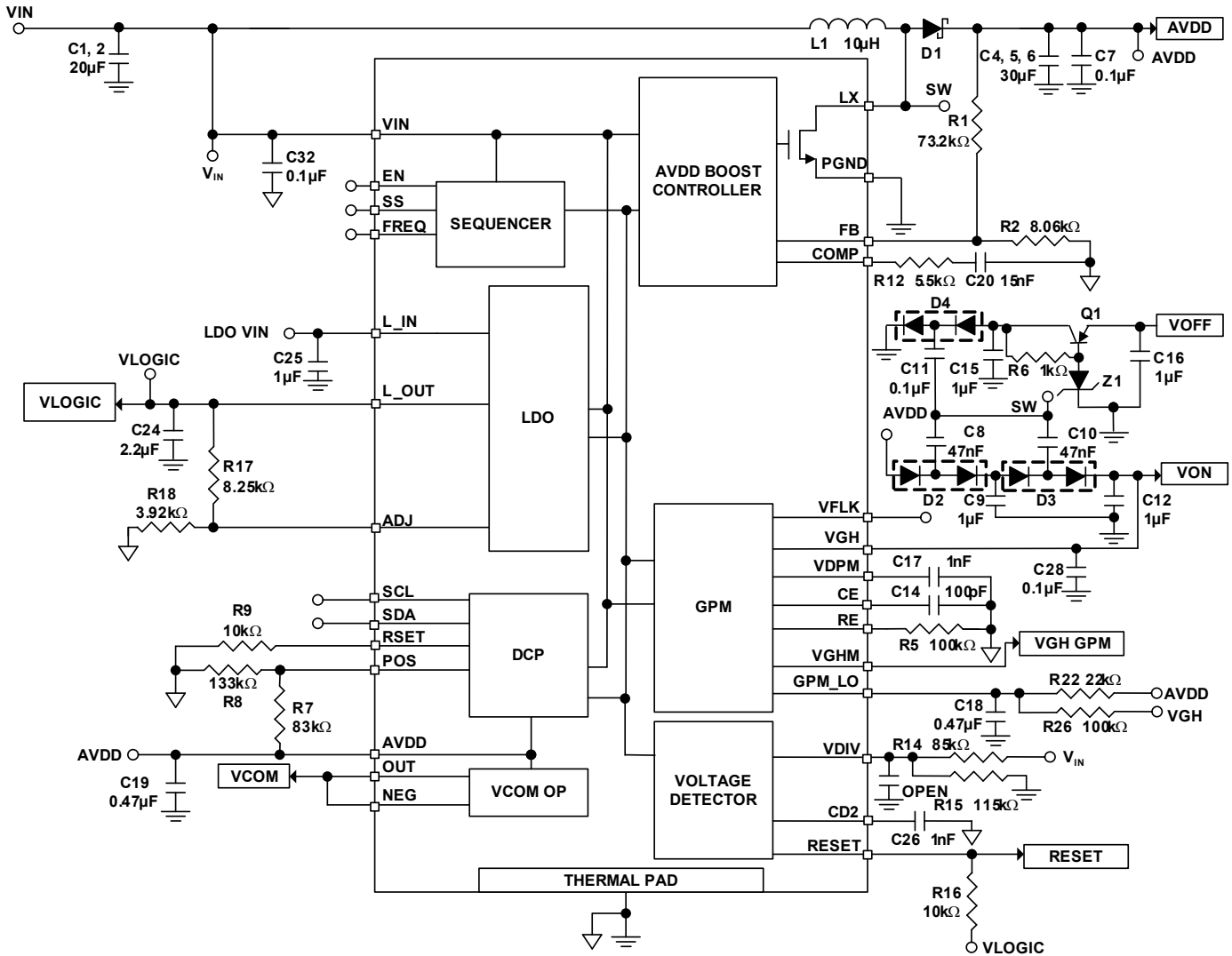
Applications

- Automotive TFT displays
 - Central displays, rear seat entertainment and dashboards

Pin Configuration



Application Diagram



Pin Descriptions

| PIN# | SYMBOL | DESCRIPTION |
|------|--------|--|
| 1 | FB | AVDD boost converter feedback. Connect to the center of a voltage divider between AVDD and GND to set the AVDD voltage. |
| 2 | PGND | Power ground |
| 3 | CE | Gate Pulse Modulator Delay Control. Connect a capacitor between this pin and GND to set the delay time. |
| 4 | RE | Gate Pulse Modulator Slew Control. Connect a resistor between this pin and GND to set the falling slew rate. |
| 5 | VGH | Gate Pulse Modulator High Voltage Input. Place a 0.1µF decoupling capacitor close to the VGH pin. |
| 6 | VGHM | Gate Pulse Modulator Output for gate driver IC |
| 7 | VFLK | Gate Pulse Modulator Control input from T _{CON} |
| 8 | VDPM | Gate Pulse Modulator Enable. Connect a capacitor from VDPM to GND to set the delay time before GPM is enabled. A current source charges the capacitor on VDPM. |
| 9 | GPM_LO | Gate Pulse Modulator Low Voltage Input; place a 0.47µF decoupling capacitor close to the GPM_LO pin. |
| 10 | AVDD | DCP and VCOM amplifier high voltage analog supply; place a 0.47µF decoupling capacitor close to the AVDD pin. |
| 11 | SCL | I ² C compatible clock input |

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Pin Descriptions (Continued)

| PIN# | SYMBOL | DESCRIPTION |
|------|--------|--|
| 12 | SDA | I ² C compatible serial bidirectional data line |
| 13 | POS | VCOM Amplifier Non-inverting input |
| 14 | RSET | DCP sink current adjustment pin; connect a resistor between this pin and GND to set the resolution of the DCP output voltage. |
| 15 | VOUT | VCOM Amplifier output |
| 16 | NEG | VCOM Amplifier inverting input |
| 17 | VDIV | Voltage detector threshold. Connect to the center of a resistive divider between V _{IN} and GND. |
| 18 | ADJ | VLOGIC LDO feedback. Connect to the center of a resistive divider between L_OUT and GND to set V _{Logic} voltage for T _{CON} . |
| 19 | RESET | Voltage detector reset output |
| 20 | L_OUT | LDO output. Connect at least one 1μF capacitor to GND for stable operation. |
| 21 | CD2 | Voltage detector rising edge delay. Connect a capacitor between this pin and GND to set the rising edge delay. |
| 22 | L_IN | LDO input. Connect a 1μF decoupling capacitor close to this pin. |
| 23 | SS | Boost Converter Soft-Start. Connect a capacitor between this pin and GND to set the soft-start time. |
| 24 | COMP | Boost converter compensation pin. Connect a series resistor and capacitor between this pin and GND to optimize transient response and stability. |
| 25 | FREQ | Boost Converter frequency select; pull it to logic high to operate boost at 1.2MHz. Connect this pin to GND to operate boost at 600kHz. |
| 26 | VIN | IC input supply. Connect a 0.1μF decoupling capacitor close to this pin. |
| 27 | LX | AVDD boost converter switching node |
| 28 | EN | AVDD enable pin |

Ordering Information

| PART NUMBER (Notes 1, 2, 3) | PART MARKING | V _{IN} RANGE (V) | TEMP RANGE (°C) | PACKAGE (Pb-free) | PKG. DWG. # |
|--------------------------------|-----------------|------------------------------|--------------------|----------------------|----------------|
| ISL78419ARZ | 78419 ARZ | 2.5 to 5.5 | -40 to +105 | 28 Ld 4x5 QFN | L28.4x5A |

NOTES:

1. Add "-T*" suffix for tape and reel. Please refer to [TB347](#) for details on reel specifications.
2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
3. For Moisture Sensitivity Level (MSL), please see device information page for [ISL78419](#) For more information on MSL please see techbrief [TB363](#).

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Absolute Maximum Ratings

| | |
|--|---------------|
| RE, VGHM, GPM_LO and VGH to GND | -0.3 to +36V |
| LX, AVDD, POS, NEG, VOUT to GND | -0.3 to +18V |
| Voltage Between GND and PGND | ±0.5V |
| All Other Pins to GND | -0.3 to +6.0V |
| ESD Rating | |
| Human Body Model (Tested per JESD22-A114E) | 2kV |
| Machine Model (Tested per JESD22-A115-A) | 200V |
| Charged Device Model (Tested per JESD22-C101) | 1kV |
| Latch Up (Tested per JESD-78B; Class 2, Level A) | 100mA |

Thermal Information

| | | |
|------------------------------------|---|----------------------|
| Thermal Resistance (Typical) | θ_{JA} (°C/W) | θ_{JC} (°C/W) |
| 28 Ld 4x5 QFN Package (Notes 4, 5) | 38 | 4.5 |
| Ambient Temperature | -40°C to +105°C | |
| Functional Junction Temperature | -40°C to +150°C | |
| Storage Temperature | -65°C to +150°C | |
| Lead Temperature During Soldering | +260°C | |
| Pb-Free Reflow Profile | see link below | |
| | http://www.intersil.com/pbfree/Pb-FreeReflow.asp | |

Recommended Operating Conditions

| | |
|----------------|-----------------|
| Temperature | -40°C to +105°C |
| Supply Voltage | 2.5V to 5.5V |

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with “direct attach” features. See Tech Brief [TB379](#).
- For θ_{JC} , the “case temp” location is the center of the exposed metal pad on the package underside.

Electrical Specifications $V_{IN} = \text{ENABLE} = 3.3\text{V}$, $A_{VDD} = 8\text{V}$, $V_{LDO} = 2.5\text{V}$, $V_{ON} = 24\text{V}$, $V_{OFF} = -6\text{V}$. **Boldface limits apply over the operating temperature range, -40°C to +105°C.**

| SYMBOL | PARAMETER | TEST CONDITIONS | MIN (Note 6) | TYP (Note 7) | MAX (Note 6) | UNITS |
|--|--|--|--------------|--------------|--------------|-------|
| GENERAL | | | | | | |
| V_{IN} | V_{IN} Supply Voltage Range | | 2.5 | 3.3 | 5.5 | V |
| I_{S_DIS} | V_{IN} Supply Currents when Disabled | $V_{IN} < UVLO$ | | 390 | 500 | μA |
| I_S | V_{IN} Supply Currents | ENABLE = 3.3V, overdrive AVDD and VGH | | 0.7 | 1.0 | mA |
| I_{ENABLE} | ENABLE Pin Current | ENABLE = 0V | | 0 | | μA |
| LOGIC INPUT CHARACTERISTICS - ENABLE, FLK, SCL, SDA, FREQ | | | | | | |
| V_{IL} | Low Voltage Threshold | | | | 0.65 | V |
| V_{IH} | High Voltage Threshold | | 1.75 | | | V |
| R_{IL} | Pull-Down Resistor | Enable, FLK, FREQ | 0.85 | 1.25 | 1.65 | MΩ |
| INTERNAL OSCILLATOR | | | | | | |
| F_{OSC} | Switching Frequencies | FREQ = low, $T_A = +25^\circ\text{C}$ | 550 | 600 | 650 | kHz |
| | | FREQ = high, $T_A = +25^\circ\text{C}$ | 1100 | 1200 | 1300 | kHz |
| AVDD BOOST REGULATOR | | | | | | |
| DAVDD/ DIOUT | AVDD Load Regulation | $50\text{mA} < I_{LOAD} < 250\text{mA}$ | | 0.2 | | % |
| DAVDD/ DVIN | AVDD Line Regulation | $I_{LOAD} = 150\text{mA}$, $2.5\text{V} < V_{IN} < 5.5\text{V}$ | | 0.15 | | % |
| V_{FB} | Feedback Voltage (V_{FB}) | $I_{LOAD} = 100\text{mA}$, $T_A = +25^\circ\text{C}$ | 0.792 | 0.8 | 0.808 | V |
| I_{FB} | FB Input Bias Current | | | | 100 | nA |
| $r_{DS(ON)}$ | Switch ON-resistance | $T_A = +25^\circ\text{C}$ | | 180 | 260 | mΩ |
| I_{LIM} | Switch Current Limit | | 1.125 | 1.5 | 1.875 | A |
| D_{MAX} | Max Duty Cycle | Freq = 1.2MHz | 80 | 90 | | % |
| EFF | | Freq = 1.2MHz, $I_{AVDD} = 100\text{mA}$ | | 91 | | % |

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| SYMBOL | PARAMETER | TEST CONDITIONS | MIN (Note 6) | TYP (Note 7) | MAX (Note 6) | UNITS |
|--|----------------------------------|---|-----------------|-----------------|-----------------|---------------|
| LDO REGULATOR | | | | | | |
| $\frac{DV_{LDO}}{DV_{IN}}$ | Line Regulation | $ILDO = 1\text{mA}$, $3.0\text{V} < V_{IN1} < 5.5\text{V}$ | | 1 | | mV/V |
| $\frac{DV_{LDO}}{DI_{OUT}}$ | Load Regulation | $1\text{mA} < ILDO < 350\text{mA}$ | | 0.2 | | % |
| V_{DO} | Dropout Voltage | Output drops by 2%, $ILDO = 350\text{mA}$ | | 225 | 300 | mV |
| I_{LIML} | Current Limit | Output drops by 5% | 330 | 425 | | mA |
| V_{ADJ} | ADJ Reference Voltage | $I_{LOAD} = 50\text{mA}$, $T_A = +25^{\circ}\text{C}$ | 0.792 | 0.8 | 0.808 | V |
| I_{ADJ} | ADJ Input Bias Current | | | | 0.1 | μA |
| GATE PULSE MODULATOR | | | | | | |
| V_{GH} | VGH Voltage | | 7 | | 33 | V |
| V_{IH_VDPM} | VdPM Enable Threshold | | 1.13 | 1.215 | 1.30 | V |
| I_{VGH} | VGH Input Current | VFLK = 0 | | 125 | | μA |
| | | RE = 100k Ω , VFLK = V_{IN} | | 27.5 | | μA |
| V_{GPM_LO} | GPM_LO Voltage | | 2 | | VGH-2 | V |
| I_{GPM_LO} | VGPM_LO Input Current | | -2 | 0.1 | 2 | μA |
| V_{CEth1} | CE Threshold Voltage 1 | | | 0.6xVIN | 0.8xVIN | V |
| V_{CEth2} | CE Threshold Voltage 2 | | | 1.215 | | V |
| I_{CE} | CE Current | | | 100 | | μA |
| R_{VGHM_PD} | VGHM Pull-down Resistance | | | 1.1 | | k Ω |
| R_{ONVGH} | VGH to VGHM On-resistance | | | 23 | | Ω |
| IDPM | VDPM Charge Current | | | 10 | | μA |
| SUPPLY MONITOR | | | | | | |
| V_{IH_VDIV} | VDIV High Threshold | VDIV rising | 1.265 | 1.280 | 1.295 | V |
| V_{IL_VDIV} | VDIV Low Threshold | VDIV falling | 1.21 | 1.222 | 1.234 | V |
| V_{thCD2} | CD2 Threshold voltage | | 1.200 | 1.217 | 1.234 | V |
| I_{CD2} | CD2 Charge Current | | | 10 | | μA |
| R_{IL_RESET} | RESET Pull-down Resistance | | | 650 | | Ω |
| t_{DELAY_RESET} | RESET Delay on the Rising Edge | | | 121.7k* | | s |
| VCOM AMPLIFIER $R_{LOAD} = 10\text{k}\Omega$, $C_{LOAD} = 10\text{pF}$, unless otherwise stated | | | | | | |
| I_{S_com} | VCOM Amplifier Supply Current | | | 0.7 | 1.08 | mA |
| V_{OS} | Offset Voltage | | | 2.5 | 15 | mV |
| I_B | Non-inverting Input Bias Current | | | 0 | | nA |
| CMIR | Common Mode Input Voltage Range | | 0 | | AVDD | V |
| CMRR | Common-Mode Rejection Ratio | | 60 | 75 | | dB |
| PSRR | Power Supply Rejection Ratio | | 70 | 85 | | dB |
| V_{OH} | Output Voltage Swing High | $I_{OUT(\text{source})} = 0.1\text{mA}$ | | AVDD - 1.39 | | mV |
| | | $I_{OUT(\text{source})} = 75\text{mA}$ | | AVDD - 1.27 | | V |
| V_{OL} | Output Voltage Swing Low | $I_{OUT(\text{sink})} = 0.1\text{mA}$ | | 1.2 | | mV |
| | | $I_{OUT(\text{sink})} = 75\text{mA}$ | | 1 | | V |

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| SYMBOL | PARAMETER | TEST CONDITIONS | MIN (Note 6) | TYP (Note 7) | MAX (Note 6) | UNITS |
|---|---|-----------------------------|-----------------|-----------------|-----------------|--------------------|
| I_{SC} | Output Short Circuit Current | Pull-up | 150 | 225 | | mA |
| | | Pull-down | 150 | 200 | | mA |
| SR | Slew Rate | | | 25 | | V/ μs |
| BW | Gain Bandwidth | -3dB gain point | | 20 | | MHz |
| DIGITAL CONTROLLED POTENTIOMETER | | | | | | |
| SET_{VR} (Note 12) | SET Voltage Resolution | | | 8 | | Bits |
| SET_{DNL} (Notes 8, 9, 14) | SET Differential Nonlinearity | $T_A = +25^{\circ}\text{C}$ | | | ± 1 | LSB |
| SET_{ZSE} (Notes 10, 14) | SET Zero-Scale Error | $T_A = +25^{\circ}\text{C}$ | | | ± 2 | LSB |
| SET_{FSE} (Notes 11, 14) | SET Full-Scale Error | $T_A = +25^{\circ}\text{C}$ | | | ± 8 | LSB |
| I_{RSET} | RSET Current | | | | 100 | μA |
| AVDD to SET | AVDD to SET Voltage Attenuation | | | 1:20 | | V/V |
| FAULT DETECTION THRESHOLD | | | | | | |
| V_{UVLO} | Undervoltage Lock out Threshold | PV_{IN} rising | 2.25 | 2.33 | 2.41 | V |
| | | PV_{IN} falling | 2.125 | 2.20 | 2.27 | V |
| OVP_{AVDD} (Note 13) | Boost Overvoltage Protection Off Threshold to Shutdown IC | | 15.0 | 15.5 | 16.0 | V |
| T_{OFF} | Thermal Shut-Down all Channels | Temperature rising | | 153 | | $^{\circ}\text{C}$ |
| POWER SEQUENCE TIMING | | | | | | |
| $t_{SSVLOGIC}$ | VLOGIC Soft-start Time | | | 0.45 | | ms |
| I_{SS} | Boost Soft-start Current | | 3 | 5.5 | 8 | μA |

Serial Interface Specifications

For SCL and SDA Unless Otherwise Noted.

| SYMBOL | PARAMETER | TEST CONDITIONS | MIN (Note 14) | TYP (Note 7) | MAX (Note 14) | UNITS |
|-----------------------|--|--|------------------|-----------------|------------------|-------|
| f_{SCL} (Note 6) | SCL Frequency | | | | 400 | kHz |
| t_{IN} (Note 6) | Pulse Width Suppression Time at SDA and SCL Inputs | Any pulse narrower than the maximum specification is suppressed | | | 50 | ns |
| t_{AA} | SCL Falling Edge to SDA Output Data Valid | SCL falling edge crossing 30% of V_{IN} , until SDA exits the 30% to 70% of V_{IN} window | | | 480 | ns |
| t_{BUF} | Time the Bus Must be Free Before the Start of a New Transmission | SDA crossing 70% of V_{CC} during a STOP condition, to SDA crossing 70% of V_{IN} during the following START condition | 480 | | | ns |
| t_{LOW} | Clock LOW Time | Measured at the 30% of V_{IN} crossing | 480 | | | ns |
| t_{HIGH} | Clock HIGH Time | Measured at the 70% of V_{IN} crossing | 400 | | | ns |
| $t_{SU:STA}$ | START Condition Set-up Time | SCL rising edge to SDA falling edge; both crossing 70% of V_{IN} | 480 | | | ns |
| $t_{HD:STA}$ | START Condition Hold Time | From SDA falling edge crossing 30% of V_{IN} to SCL falling edge crossing 70% of V_{IN} | 400 | | | ns |

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Serial Interface Specifications For SCL and SDA Unless Otherwise Noted. (Continued)

| SYMBOL | PARAMETER | TEST CONDITIONS | MIN (Note 14) | TYP (Note 7) | MAX (Note 14) | UNITS |
|--------------|---|---|------------------|-----------------|------------------|-------|
| $t_{SU:DAT}$ | Input Data Set-up Time | From SDA exiting the 30% to 70% of V_{IN} window, to SCL rising edge crossing 30% of V_{IN} | 40 | | | ns |
| $t_{HD:DAT}$ | Input Data Hold Time | From SCL rising edge crossing 70% of V_{IN} to SDA entering the 30% to 70% of V_{IN} window | 0 | | | ns |
| $t_{SU:STO}$ | STOP Condition Set-up Time | From SCL rising edge crossing 70% of V_{IN} , to SDA rising edge crossing 30% of V_{IN} | 400 | | | ns |
| $t_{HD:STO}$ | STOP Condition Hold Time for Read, or Volatile Only Write | From SDA rising edge to SCL falling edge; both crossing 70% of V_{IN} | 400 | | | ns |
| C_{SCL} | Capacitive on SCL | | | 5 | | pF |
| C_{SDA} | Capacitive on SDA | | | 5 | | pF |
| t_{Wp} | Non-Volatile Write Cycle Time | | | 25 | | ms |
| | EEPROM Endurance | $T_A = +25^\circ\text{C}$ | | 1 | | kCyc |
| | EEPROM Retention | $T_A = +25^\circ\text{C}$ | | 88 | | kHrs |

NOTES:

- Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.
- Typical values are for $T_A = +25^\circ\text{C}$ and $V_{IN} = 3.3\text{V}$.
- $LSB = |V_{255} - V_1|/254$. V_{255} and V_1 are the measured voltages for the DCP register set to FF hex and 01 hex respectively.
- $DNL = |V_{i+1} - V_i|/LSB - 1$, $i \in [1, 255]$
- $ZS\ error = (V_1 - V_{MIN})/LSB$. $V_{MIN} = (V_{AVDD} * R2) * [1 - 254 * R1 / (255 * 20 * RSET)] / (R1 + R2)$.
- $FS\ error = (V_{255} - V_{MAX})/LSB$. $V_{MAX} = (V_{AVDD} * R2) * [1 - 0 * R1 / (255 * 20 * RSET)] / (R1 + R2)$.
- Established by design. Not a parametric spec.
- Boost will stop switching as soon as boost output reaches OVP threshold.
- Compliance to limits is assured by characterization and design.

Typical Performance Curves

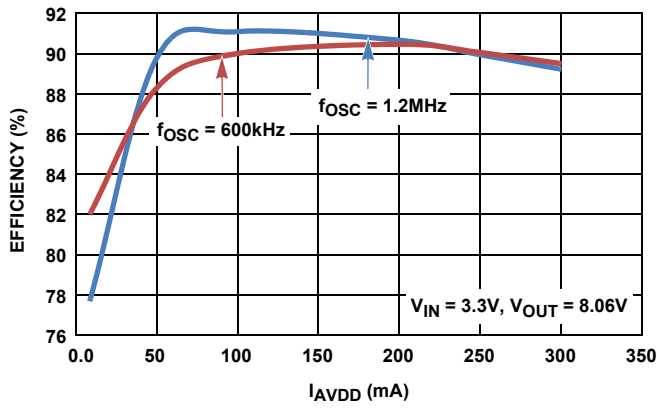


FIGURE 1. AVDD EFFICIENCY vs I_{AVDD}

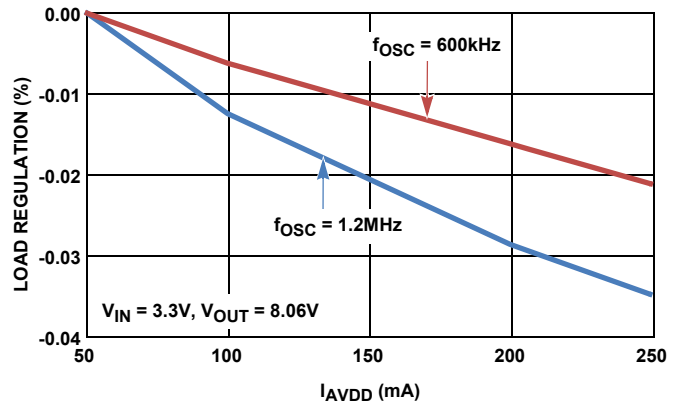


FIGURE 2. AVDD LOAD REGULATION vs I_{AVDD}

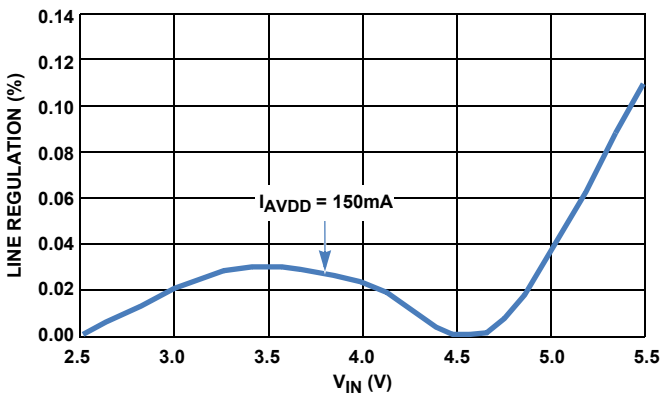


FIGURE 3. AVDD LINE REGULATION vs V_{IN}

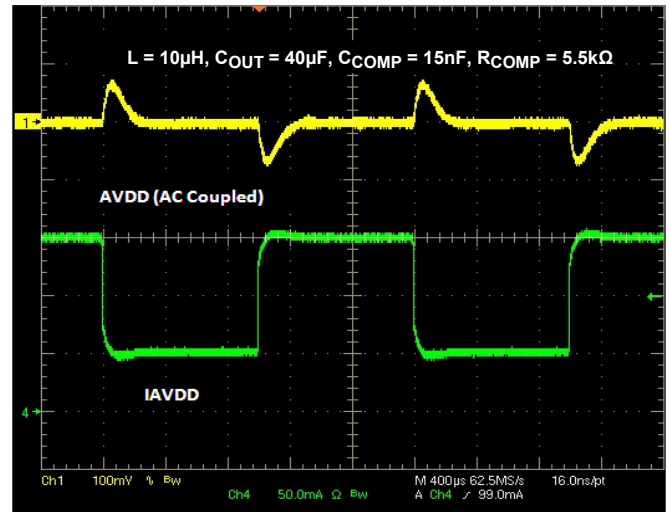


FIGURE 4. BOOST CONVERTER TRANSIENT RESPONSE

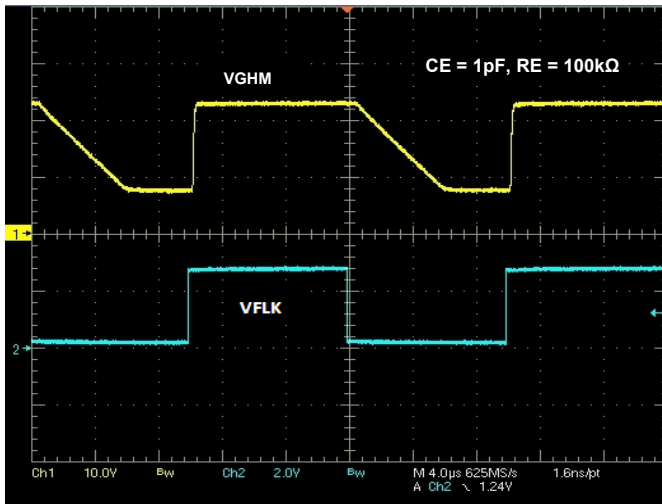


FIGURE 5. GPM CIRCUIT WAVEFORM

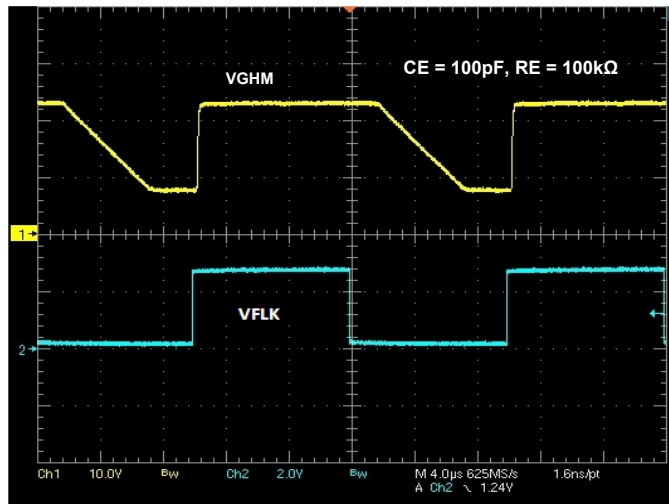


FIGURE 6. GPM CIRCUIT WAVEFORM

Typical Performance Curves (Continued)

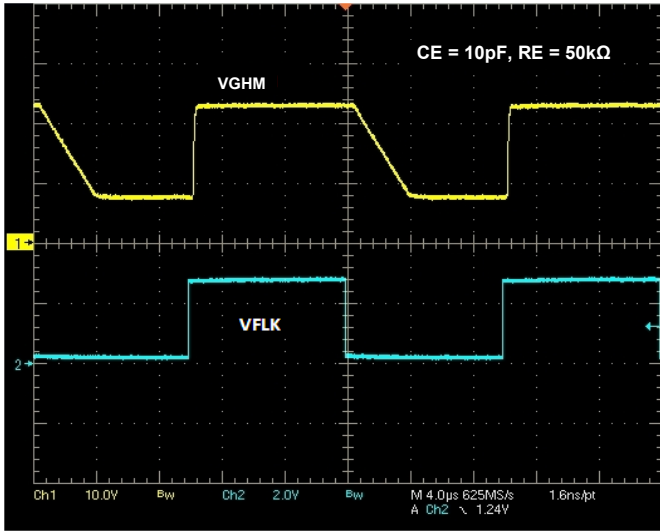


FIGURE 7. GPM CIRCUIT WAVEFORM

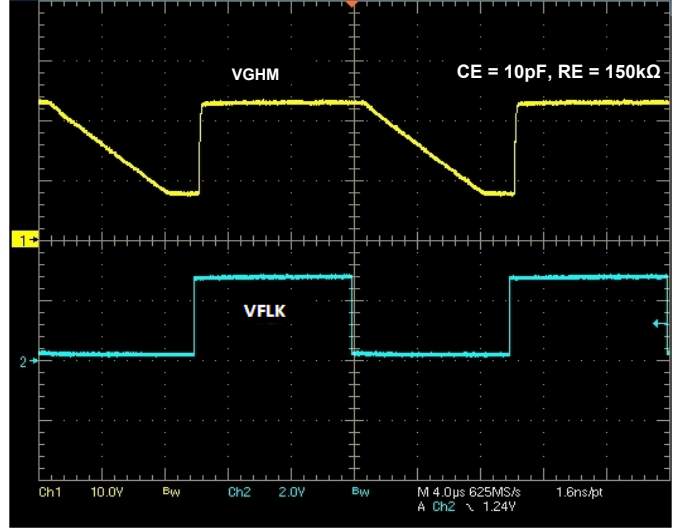


FIGURE 8. GPM CIRCUIT WAVEFORM

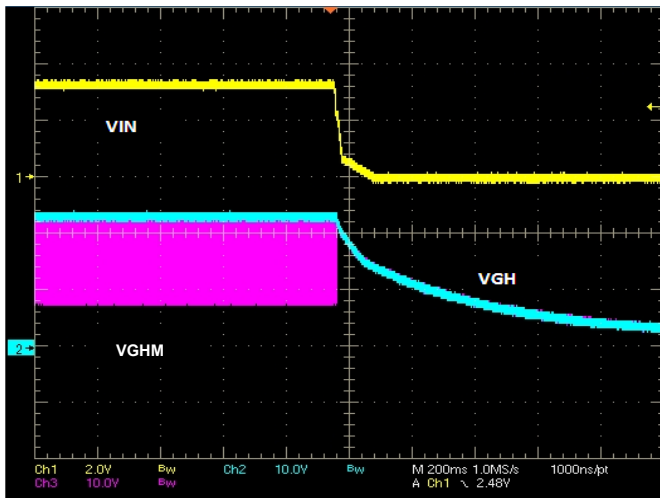


FIGURE 9. V_{GHM} FOLLOWS V_{GH} WHEN THE SYSTEM POWERS OFF

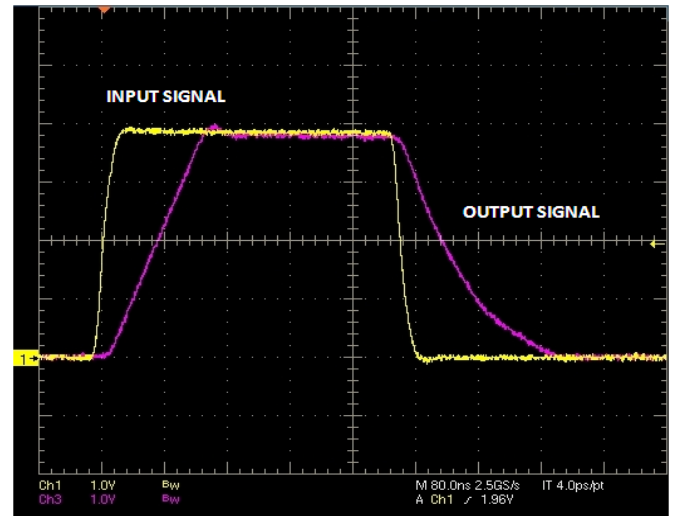


FIGURE 10. VCOM RISING SLEW RATE

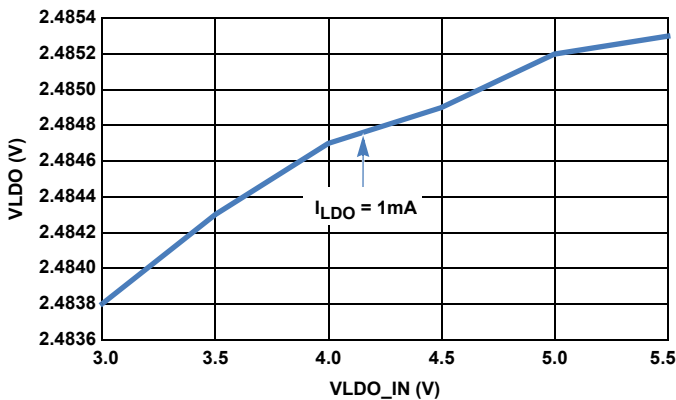


FIGURE 11. LDO LINE REGULATION vs V_{IN}

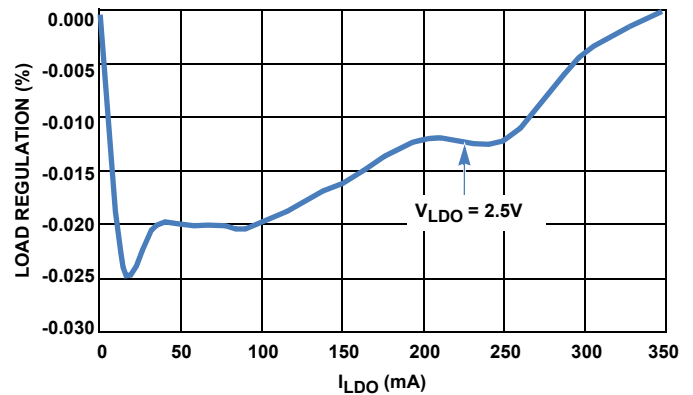


FIGURE 12. LDO LOAD REGULATION vs I_{LDO}

Applications Information

Enable Control

With $V_{IN} > UVLO$, only the Logic output channel is activated. All other functions in ISL78419 are shut down when the enable pin is pulled down. When the voltage at the enable pin reaches high threshold, the whole chip turns on.

Frequency Selection

The ISL78419 switching frequency can be user selected to operate at either constant 600kHz or 1.2MHz. Lower switching frequency can save power dissipation at very light load conditions. Also, low switching frequency more easily leads to discontinuous conduction mode, while higher switching frequency allows for smaller external components, such as inductor and output capacitors, etc. Higher switching frequency will get higher efficiency within some loading ranges depending on V_{IN} , V_{OUT} , and external components, as shown in Figure 1. Connecting the $FREQ$ pin to GND sets the PWM switching frequency to 600kHz, or connecting $FREQ$ pin to V_{IN} for 1.2MHz.

Soft-Start

The soft-start is provided by an internal current source to charge the external soft-start capacitor. The ISL78419 ramps up the current limit from 0A up to the full value, as the voltage at the SS pin ramps from 0V to 0.8V. Hence, the soft-start time is 3.2ms when the soft-start capacitor is 22nF, 6.8ms for 47nF and 14.5ms for 100nF.

Operation

The boost converter is a current mode PWM converter operating at either 600kHz or 1.2MHz. It can operate in both discontinuous conduction mode (DCM) at light load and continuous conduction mode (CCM). In continuous conduction mode, current flows continuously in the inductor during the entire switching cycle in steady state operation. The voltage conversion ratio in continuous current mode is given by Equation 1:

$$\frac{V_{Boost}}{V_{IN}} = \frac{1}{1-D} \quad (EQ. 1)$$

Where D is the duty cycle of the switching MOSFET.

The boost regulator uses a summing amplifier architecture consisting of gm stages for voltage feedback, current feedback and slope compensation. A comparator looks at the peak inductor current cycle-by-cycle and terminates the PWM cycle if the current limit is reached.

An external resistor divider is required to divide the output voltage down to the nominal reference voltage. Current drawn by the resistor network should be limited to maintain the overall converter efficiency. The maximum value of the resistor network is limited by the feedback input bias current and the potential for noise being coupled into the feedback pin. A resistor network in the order of 60kΩ is recommended. The boost converter output voltage is determined by Equation 2:

$$V_{Boost} = \frac{R_1 + R_2}{R_2} \times V_{FB} \quad (EQ. 2)$$

The current through the MOSFET is limited to 1.5A_{PEAK}.

This restricts the maximum output current (average) based on Equation 3:

$$I_{OMAX} = \left(I_{LMT} - \frac{\Delta I_L}{2} \right) \times \frac{V_{IN}}{V_O} \quad (EQ. 3)$$

Where ΔI_L is the peak-to-peak inductor ripple current, and is set by Equation 4:

$$\Delta I_L = \frac{V_{IN}}{L} \times \frac{D}{f_s} \quad (EQ. 4)$$

Where f_s is the switching frequency (600kHz or 1.2MHz).

Capacitor

An input capacitor is used to suppress the voltage ripple injected into the boost converter. The ceramic capacitor with a capacitance larger than 10μF is recommended. The voltage rating of the input capacitor should be larger than the maximum input voltage. Some input capacitors are recommended in Table 1.

TABLE 1. BOOST CONVERTER INPUT CAPACITOR RECOMMENDATION

| CAPACITOR | SIZE | MFG | PART NUMBER |
|-----------|------|--------|----------------|
| 10μF/6.3V | 0603 | TDK | C1608X5R0J106M |
| 10μF/16V | 1206 | TDK | C3216X7R1C106M |
| 10μF/10V | 0805 | Murata | GRM21BR61A106K |
| 22μF/10V | 1210 | Murata | GRB32ER61A226K |

Inductor

The boost inductor is a critical part that influences the output voltage ripple, transient response, and efficiency. Values of 3.3μH to 10μH are used to match the internal slope compensation. The inductor must be able to handle the following average and peak currents shown in Equation 5:

$$I_{LAVG} = \frac{I_O}{1-D} \quad (EQ. 5)$$

$$I_{LPK} = I_{LAVG} + \frac{\Delta I_L}{2}$$

Some inductors are recommended in Table 2 for different design considerations.

Rectifier Diode

A high-speed diode is necessary due to the high switching frequency. Schottky diodes are recommended because of their fast recovery time and low forward voltage. The reverse voltage rating of this diode should be higher than the maximum output voltage. The rectifier diode must meet the output current and peak inductor current requirements. Table 3 shows some recommendations for boost converter diode.

TABLE 2. BOOST CONVERTER INDUCTOR RECOMMENDATION

| INDUCTOR | DIMENSIONS (mm) | MFG | PART NUMBER | NOTE |
|--------------------------------|-----------------|--------|------------------|--------------------------------|
| 10μH/ 4A _{peak} | 8.3x8.3x4.5 | Sumida | CDR8D43-100NC | Efficiency optimization |
| 6.8μH/ 1.8A _{peak} | 5.0x5.0x2.0 | TDK | PLF5020T-6R8M1R8 | |
| 10μH/ 2.2A _{peak} | 6.6x7.3x1.2 | Cyntec | PCME061B-100MS | PCB space/profile optimization |

TABLE 3. BOOST CONVERTER RECTIFIER DIODE RECOMMENDATION

| DIODE | V _R /I _{AVG} RATING | PACKAGE | MFG |
|------------|---|----------|--------|
| PMEG2010ER | 20V/1A | SOD123W | NXP |
| MSS1P2U | 20V/1A | MicroSMP | VISHAY |

Output Capacitor

The output capacitor supplies the load directly and reduces the ripple voltage at the output. Output ripple voltage consists of two components:

1. The voltage drop due to the inductor ripple current flowing through the ESR of the output capacitor.
2. Charging and discharging of the output capacitor.

$$V_{\text{RIPPLE}} = I_{\text{LPK}} \times \text{ESR} + \frac{V_{\text{O}} - V_{\text{IN}}}{V_{\text{O}}} \times \frac{I_{\text{O}}}{C_{\text{OUT}}} \times \frac{1}{f_{\text{s}}} \quad (\text{EQ. 6})$$

For low ESR ceramic capacitors, the output ripple is dominated by the charging and discharging of the output capacitor. The voltage rating of the output capacitor should be greater than the maximum output voltage.

Note: Capacitors have a voltage coefficient that makes their effective capacitance drop as the voltage across them increases. C_{OUT} in Equation 6 assumes the effective value of the capacitor at a particular voltage and not the manufacturer's stated value, measured at 0V.

Table 4 shows some selections of output capacitors.

TABLE 4. BOOST OUTPUT CAPACITOR RECOMMENDATION

| CAPACITOR | SIZE | MFG | PART NUMBER |
|-----------|------|--------|----------------|
| 10μF/25V | 1210 | TDK | C3225X7R1E106M |
| 10μF/25V | 1210 | Murata | GRM32DR61E106K |

Compensation

The boost converter of ISL78419 can be compensated by an RC network connected from the COMP pin to ground. A 15nF and 5.5kΩ RC network is used in the evaluation. The larger value resistor and lower value capacitor can lower the transient overshoot, however, at the expense of the stability of the loop.

Linear Regulator (LDO)

The ISL78419 includes an LDO with adjustable output. It can supply current up to 350mA. The output voltage is adjusted by connection of the ADJ pin.

The efficiency of the LDO depends on the difference between input voltage and output voltage (Equation 7) by assuming LDO quiescent current is much lower than LDO output current:

$$\eta(\%) = \left(\frac{V_{\text{LDO_IN}}}{V_{\text{LDO_OUT}}} \right) \times 100\% \quad (\text{EQ. 7})$$

The less difference between input and output voltage, the higher efficiency it is.

Ceramic capacitors are recommended for the LDO input and output capacitors. Intersil recommends an output capacitor within the 1μF to 4.7μF range and a maximum feedback resistor impedance of 20kΩ. Larger capacitors help to reduce noise and deviation during transient load change. Some capacitors are recommended in Table 5.

TABLE 5. LDO OUTPUT CAPACITOR RECOMMENDATION

| CAPACITOR | SIZE | MFG | PART NUMBER |
|------------|------|--------|----------------|
| 1μF/10V | 0603 | TDK | C1608X7R1A105K |
| 1μF/6.3V | 0603 | MURATA | GRM188R70J105K |
| 2.2μF/6.3V | 0603 | TDK | C1608X7R0J225K |

Supply Monitor Circuit

The Supply Monitor circuit monitors the voltage on VDIV, and sets open-drain output RESET low when VDIV is below 1.28V (rising) or 1.22V (falling).

There is a delay on the rising edge, controlled by a capacitor on CD2. When VDIV exceeds 1.28V (rising), CD2 is charged up from 0V to 1.217V by a 10μA current source. Once CD2 exceeds 1.217V, RESET will go tri-state. When VDIV falls below 1.22V, RESET will become low with a 650Ω pull-down resistance. The delay time is controlled by Equation 8:

$$t_{\text{delay}} = 121.7\text{k} \times \text{CD2} \quad (\text{EQ. 8})$$

For example, the delay time is 12.17ms if the CD2 = 100nF.

Figure 13 shows the Supply Monitor Circuit timing diagram.

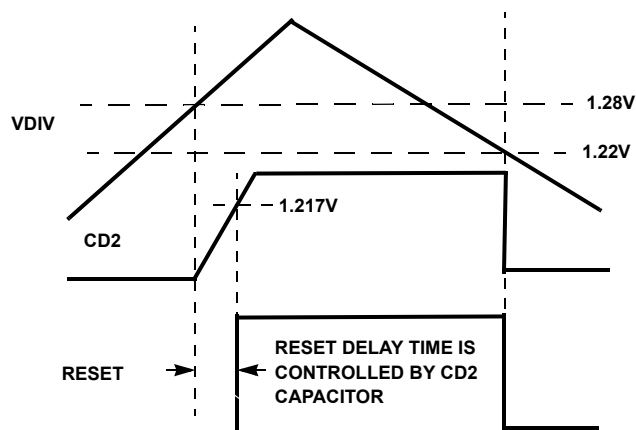


FIGURE 13. SUPPLY MONITOR CIRCUIT TIMING DIAGRAM

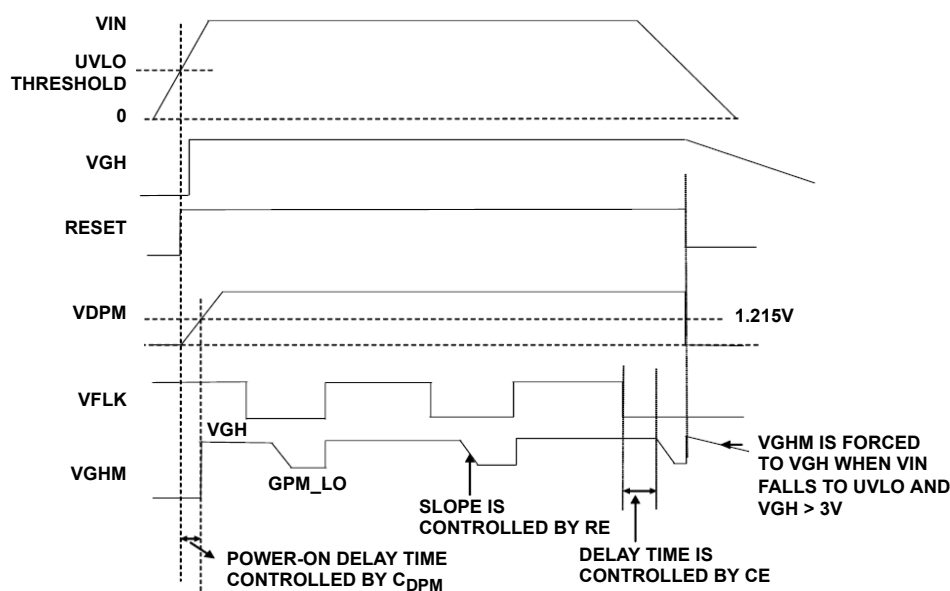


FIGURE 14. GATE PULSE MODULATOR TIMING DIAGRAM

Gate Pulse Modulator Circuit

The gate pulse modulator circuit functions as a three way multiplexer, switching VGHM between ground, GPM_LO and VGH. Voltage selection is provided by digital inputs VDPM (enable) and VFLK (control). High to low delay and slew control is provided by external components on pins CE and RE, respectively.

When VDPM is LOW, the block is disabled and VGHM is grounded. When the input voltage exceeds UVLO threshold, VDPM starts to drive an external capacitor. Once VDPM exceeds 1.215V, the GPM circuit is enabled, and the output VGHM is determined by VFLK, RESET signal and VGH voltage. If the RESET signal is high and VFLK is high, VGHM is pulled to VGH. When VFLK goes low, there is a delay controlled by capacitor CE, following which, VGHM is driven to GPM_LO, with a slew rate controlled by resistor RE. Note that GPM_LO is used only as a reference voltage for an amplifier, and thus does not have to source or sink a significant DC current.

Low to high transition is determined primarily by the switch resistance and the external capacitive load. High to low transition is more complex. Take the case where the block is already enabled (VDPM is high). When VFLK is high, if CE is not externally pulled above threshold voltage 1, pin CE is pulled low. On the falling edge of VFLK, a current is passed into pin CE to charge the external capacitor up to threshold voltage 2, providing a delay which is adjustable by varying the capacitor on CE. Once this threshold is reached, the output starts to be pulled down from VGH to GPM_LO. The maximum slew current is equal to $500/(RE + 40k)$, and the dv/dt slew rate is Is/C_{LOAD} , where C_{LOAD} is the load capacitance applied to VGHM. The slew rate reduces as VGHM approaches GPM_LO.

If CE is always pulled up to a voltage above threshold 1, zero delay mode is selected; thus there will be no delay from FLK falling to the point where VGHM starts to fall. Slew down currents will be identical to the previous case.

At power-down, when VIN falls to UVLO, VGHM will be tied to VGH until the VGH voltage falls to 3V. Once the VGH voltage falls below 3V, VGHM will not be actively driven until VIN is driven. Figure 14 shows the VGHM voltage based on V_{IN} , VGH and RESET.

VCOM Amplifier

The VCOM amplifier is designed to control the voltage on the back plane of an LCD display. This plane is capacitively coupled to the pixel drive voltage, which alternately cycles positive and negative at the line rate for the display. Thus, the amplifier must be capable of sourcing and sinking pulses of current, which can occasionally be quite large (in the range of 100mA for typical applications).

The ISL78419 VCOM amplifier's output current is limited to 225mA typical. This limit level, which is roughly the same for sourcing and sinking, is included to maintain reliable operation of the part. It does not necessarily prevent a large temperature rise if the current is maintained. (In this case, the whole chip may be shut down by the thermal trip to protect functionality.) If the display occasionally demands current pulses higher than this limit, the reservoir capacitor will provide the excess and the amplifier will top the reservoir capacitor back up once the pulse has stopped. This will happen in the μs time scale in practical systems and for pulses 2 or 3 times the current limit; the VCOM voltage will have settled again before the next line is processed.

DCP Memory Description

The ISL78419 contains 1 non-volatile byte known as the Initial Value Register (IVR). It is accessed by the I^2C interface operations with Address 00h. The IVR contains the value that is loaded into the Volatile Wiper Register (WR) at power-up.

The volatile WR, and the non-volatile IVR of a DCP are accessed with the same address.

The Access Control Register (ACR) determines which word at address 00h is accessed (IVR or WR). The volatile ACR must be set as follows:

- When the ACR is all zeroes, which is the default at power-up:
 - A read operation to address 0 outputs the value of the non-volatile IVR
 - A write operation to address 0 writes the identical values to the WR and IVR of the DCP
- When the ACR is 80h:
 - A read operation to address 0 outputs the value of the volatile WR
 - A write operation to address 0 only writes to the volatile WR

It is not possible to write to an IVR without writing the same value to its WR.

00h and 80h are the only values that should be written to address 2. All other values are reserved and must not be written to address 2.

TABLE 6. MEMORY MAP

| ADDRESS | NON-VOLATILE | VOLATILE |
|---------|--------------|----------|
| 2 | - | ACR |
| 1 | Reserved | |
| 0 | IVR | WR |

WR: Wiper Register, IVR: Initial value Register.

I²C Serial Interface

The ISL78419 supports a bidirectional bus oriented protocol. The protocol defines any device that sends data on to the bus as a transmitter and the receiving device as the receiver. The device controlling the transfer is a master and the device being controlled is the slave. The master always initiates data transfers and provides the clock for both transmit and receive operations. Therefore, the DCP of the ISL78419 operates as a slave device in all applications. The fall and rise time of SDA and SCL signal should be in the range listed in Table 8. Capacitive load on I²C bus is also specified in Table 8.

All communication over the I²C interface is conducted by sending the MSB of each byte of data first.

Protocol Conventions

Data states on the SDA line can change only during SCL LOW periods. SDA state changes during SCL HIGH are reserved for indicating START and STOP conditions (see Figure 15). On power-up of the ISL78419, the SDA pin is in the input mode.

All I²C interface operations must begin with a START condition, which is a HIGH to LOW transition of SDA while SCL is HIGH. The DCP continuously monitors the SDA and SCL lines for the START condition and does not respond to any command until this condition is met (see Figure 15). A START condition is ignored during the power-up sequence and during internal non-volatile write cycles.

All I²C interface must be terminated by a STOP condition, which is a LOW to HIGH transition of SDA while SCL is high (see Figure 15). A STOP condition at the end of a read operation, or at the end of a write operation to volatile bytes only places the device in its standby mode. A STOP condition during a write operation to a non-volatile write byte, initiates an internal non-volatile write cycle. The device enters its standby state when the internal non-volatile write cycle is completed.

An ACK (Acknowledge) is a software convention used to indicate a successful data transfer. The transmitting device, either master or slave, releases the SDA bus after transmitting eight bits. During the ninth clock cycle, the receiver pulls the SDA line LOW to acknowledge the reception of the eight bits of data (see Figure 16).

The ISL78419 DCP responds with an ACK after recognition of a START condition followed by a valid Identification Byte, and once again after successful receipt of an Address Byte. The ISL78419 also responds with an ACK after receiving a Data Byte of a write operation. The master must respond with an ACK after receiving a Data Byte of a read operation.

A valid Identification Byte contains 0101000 as the seven MSBs. The LSB is in the Read/Write bit. Its value is "1" for a Read operation, and "0" for a Write operation (see Table 7).

TABLE 7. IDENTIFICATION BYTE FORMAT

| | | | | | | | |
|-------|---|---|---|---|---|---|--------------|
| 0 | 1 | 0 | 1 | 0 | 0 | 0 | R/ \bar{W} |
| (MSB) | | | | | | | (LSB) |

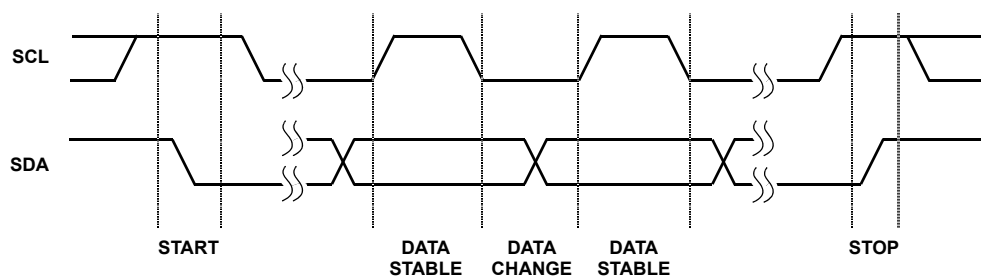


FIGURE 15. VALID DATA CHANGES, START, AND STOP CONDITIONS

ISL78419

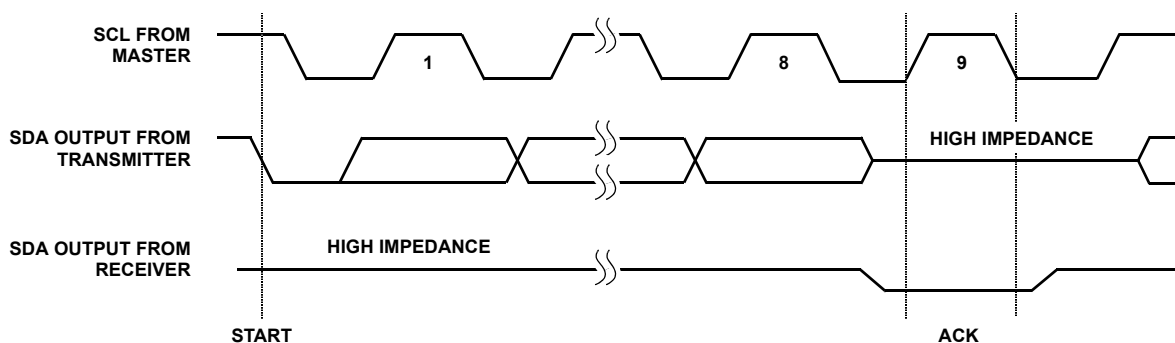


FIGURE 16. ACKNOWLEDGE RESPONSE FROM RECEIVER

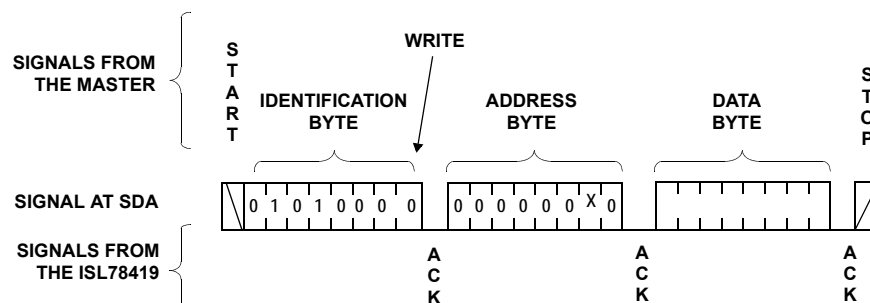


FIGURE 17. BYTE WRITE SEQUENCE

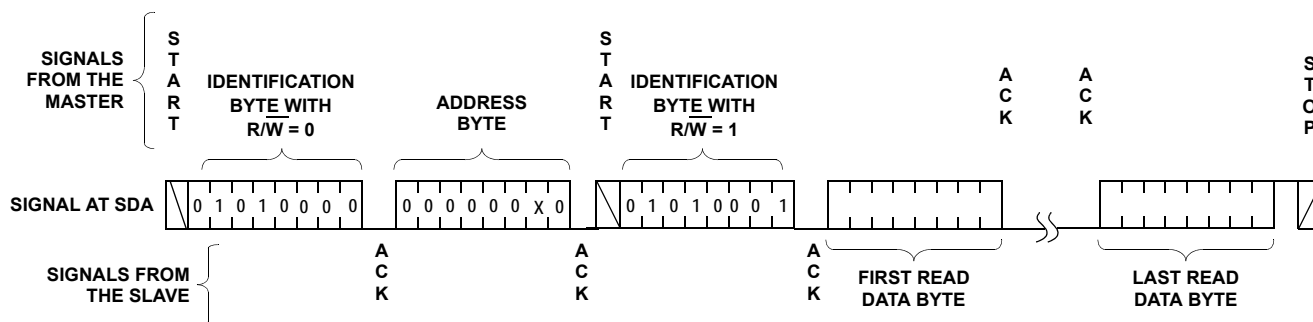


FIGURE 18. READ SEQUENCE

Write Operation

A write operation requires a START condition, followed by a valid Identification Byte, a valid Address Byte, a Data Byte, and a STOP condition (see Figure 17). After each of the three bytes, the ISL78419 responds with an ACK. At this time, if the Data Byte is to be written only to volatile registers, the device enters its standby state. If the Data Byte is to be written also to non-volatile memory, the ISL78419 begins its internal write cycle to non-volatile memory. During the internal non-volatile write cycle, the device ignores transitions at the SDA and SCL pins and the SDA output is at high impedance state. When the internal non-volatile write cycle is completed, the ISL78419 enters its standby state. The byte at address 02h determines if the Data Byte is to be written to volatile and/or non-volatile memory.

Data Protection

A STOP condition also acts as a protection of non-volatile memory. A valid Identification Byte, Address Byte, and total number of SCL pulses act as a protection of both volatile and non-volatile registers. During a Write sequence, the Data Byte is loaded into an internal shift register as it is received. If the Address Byte is 0 or 2, the Data Byte is transferred to the Wiper Register (WR) or to the Access Control Register respectively, at the falling edge of the SCL pulse that loads the last bit (LSB) of the Data Byte. If the Address Byte is 0, and the Access Control Register is all zeros (default), then the STOP condition initiates the internal write cycle to non-volatile memory.

TABLE 8. I²C INTERFACE SPECIFICATION

| PARAMETER | MIN | TYP | MAX | UNITS |
|--------------------------------------|-----|-----|------|-------|
| SDA and SCL Rise Time | | | 1000 | ns |
| SDA and SCL Fall Time | | | 300 | ns |
| I ² C Bus Capacitive Load | | | 400 | pF |

Read Operation

A read operation consists of a three byte instruction followed by one or more Data Bytes (see Figure 18). The master initiates the operation issuing the following sequence: a START, the Identification byte with the R/W bit set to "0", an Address Byte, a second START, and a second Identification byte with the R/W bit set to "1". After each of the three bytes, the ISL78419 responds with an ACK; then the ISL78419 transmits the Data Byte. The master then terminates the read operation (issuing a STOP condition) following the last bit of the Data Byte (see Figure 16).

The byte at address 02h determines if the Data Bytes being read are from volatile or non-volatile memory.

Communication with ISL78419

There are 3 register addresses in the ISL78419, of which two can be used. Address 00h and address 02h are used to control the device. Address 01h is reserved and should not be used. Address 00h contains the non-volatile Initial Value Register (IVR), and the volatile Wiper Register (WR). Address 02h contains only a volatile word and is used as a pointer to either the IVR or WR.

Register Description: Access Control

The Access Control Register (ACR) is volatile and is at address 02h. It is 8 bits, and only the MSB is significant; all other bits

should be zero (0). The ACR controls which word is accessed at register 00h as follows:

- 00h = Nonvolatile IVR
- 80h = Volatile WR

All other bits of the ACR should be written 0 or 1. Power-up default for this address is 00h.

Register Description: IVR and WR

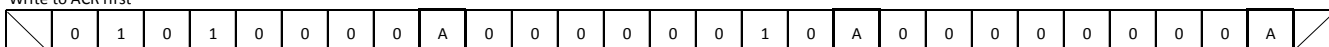
The output of the DCP is controlled directly by the WR. Writes and reads can be made directly to this register to control and monitor without any non-volatile memory changes. This is done by setting address 02h to data 80h, then writing the data.

The non-volatile IVR stores the power-up value of the DCP output. On power-up, the contents of the IVR are transferred to the WR.

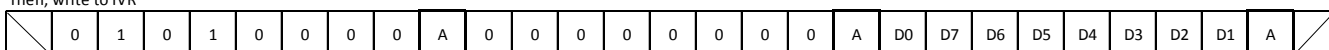
To write to the IVR, first address 02h is set to data 00h, then the data is written. Writing a new value to the IVR register will set a new power-up position for the wiper. Also, writing to this register will load the same value into the WR as the IVR. Therefore, if a new value is loaded into the IVR, not only will the non-volatile IVR change, but the WR will also contain the same value after the write, and the wiper position will change. Reading from the IVR will not change the WR, if its contents are different.

Writing a new value to the IVR

Write to ACR first



Then, write to IVR

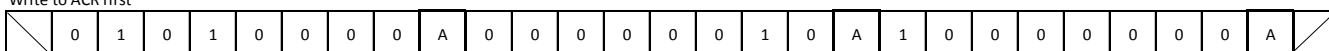


Note that the WR will also reflect this new value since both registers get written at the same time

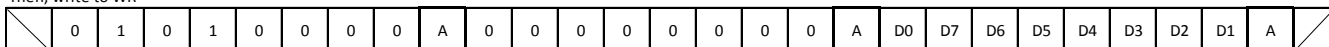
D0:LSB, D7:MSB

Writing a new value to WR only

Write to ACR first



Then, write to WR

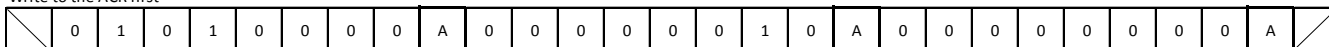


Note that the IVR value will NOT change

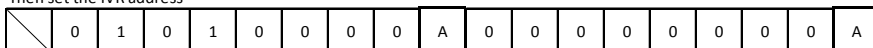
D0:LSB, D7:MSB

Reading from IVR

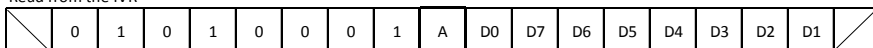
Write to the ACR first



Then set the IVR address



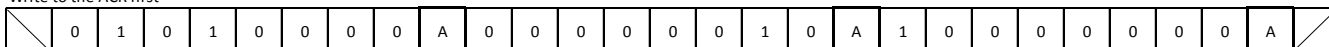
Read from the IVR



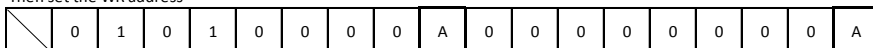
Example 2

Reading from the WR

Write to the ACR first



Then set the WR address



Read from the WR

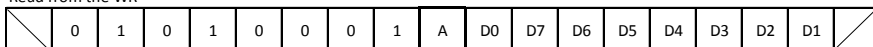


FIGURE 19.

Initial VCOM Setting

A 256-step resolution is provided under digital control, which adjusts the sink current of the output. The output is connected to an external voltage divider, so that the device will have the capability to reduce the voltage on the output by increasing the output sink current. The equations that control the output are given in the following. The initial setting value is at 128. The WR value is set back to 128 if any error occurs during I²C read or write communication. When writing to the EEPROM, VGH needs to be higher than 12V when AVDD is 8V. Outside these conditions, writing operations may be not successful. The maximum resistor value of RSET is determined by Equations 9 and 10:

$$RSET > V_{AVDD} / (20 \times 100 \mu A) \quad (\text{EQ. 9})$$

$$I_{OUT} = \frac{255 - \text{Setting}}{255} \cdot \frac{V_{AVDD}}{20(RSET)} \quad (\text{EQ. 10})$$

Where R_L, R_U and RSET in Equation 11 correspond to R₇, R₈ and R₉ in the Application Diagram on page 2.

$$V_{OUT} = \frac{R_L \cdot V_{AVDD}}{(R_U + R_L)} \cdot \left(1 - \frac{255 - \text{Setting}}{255} \times \frac{R_U}{20(RSET)} \right) \quad (\text{EQ. 11})$$

Start-up Sequence

When VIN rising exceeds UVLO, it takes 120μs to read the settings stored in the chip in order to activate the chip correctly. After all the settings are written in the registers, VLOGIC starts up with a 0.5ms soft-start time. When both VLOGIC is in regulation and EN is high, the boost converter starts up. The Gate Pulse modulator output VGHM is held low until VDPM is charged to 1.215V. The detailed power-on sequence is shown in Figure 20.

Layout Recommendation

The device's performance, including efficiency, output noise, transient response and control loop stability, is affected by the PCB layout. PCB layout is critical, especially at high switching frequency.

Following are some general guidelines for layout:

1. Place the external power components (the input capacitors, output capacitors, boost inductor and output diodes, etc.) in close proximity to the device. Traces to these components should be kept as short and wide as possible to minimize parasitic inductance and resistance.
2. Place V_{DC} and V_{REF} bypass capacitors close to the pins.
3. Loops with large AC amplitudes and fast slew rate should be made as small as possible.
4. The feedback network should sense the output voltage directly from the point of load, and be as far away from the LX node as possible.
5. The power ground (PGND) should be connected at the ISL78419 exposed die plate area.
6. The exposed die plate, on the underside of the package, should be soldered to an equivalent area of metal on the PCB. This contact area should have multiple via connections to the back of the PCB, as well as connections to intermediate PCB layers, if available, to maximize thermal dissipation away from the IC.
7. To minimize the thermal resistance of the package when soldered to a multi-layer PCB, the amount of copper track and ground plane area connected to the exposed die plate should be maximized and spread out as far as possible from the IC. The bottom and top PCB areas especially should be maximized to allow thermal dissipation to the surrounding air.
8. Minimize feedback input track lengths to avoid switching noise pick-up.

ISL78419

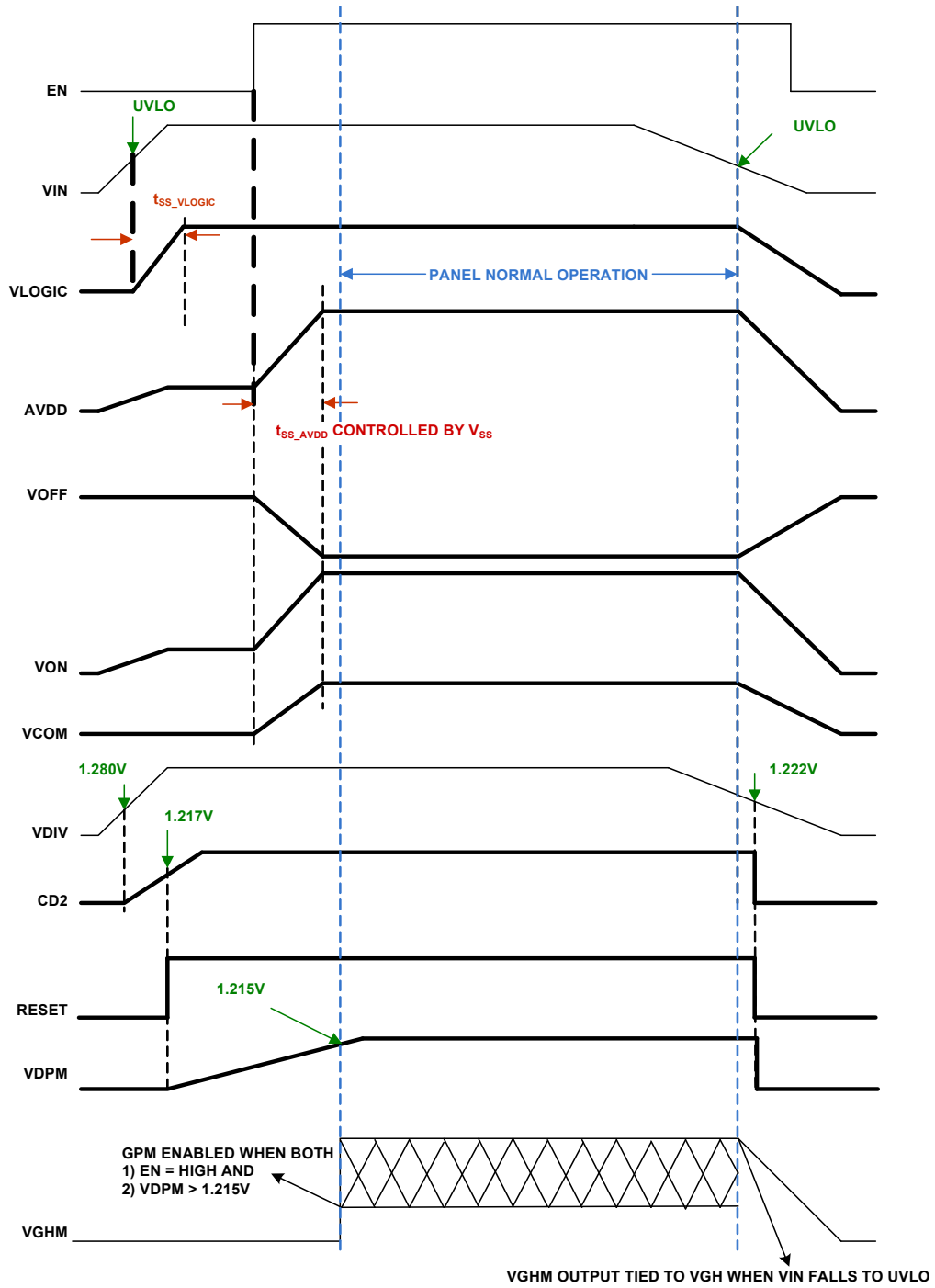


FIGURE 20. ISL78419 POWER ON/OFF SEQUENCE

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

| DATE | REVISION | CHANGE |
|------------------|----------|------------------|
| December 3, 2012 | FN8292.1 | Initial Release. |

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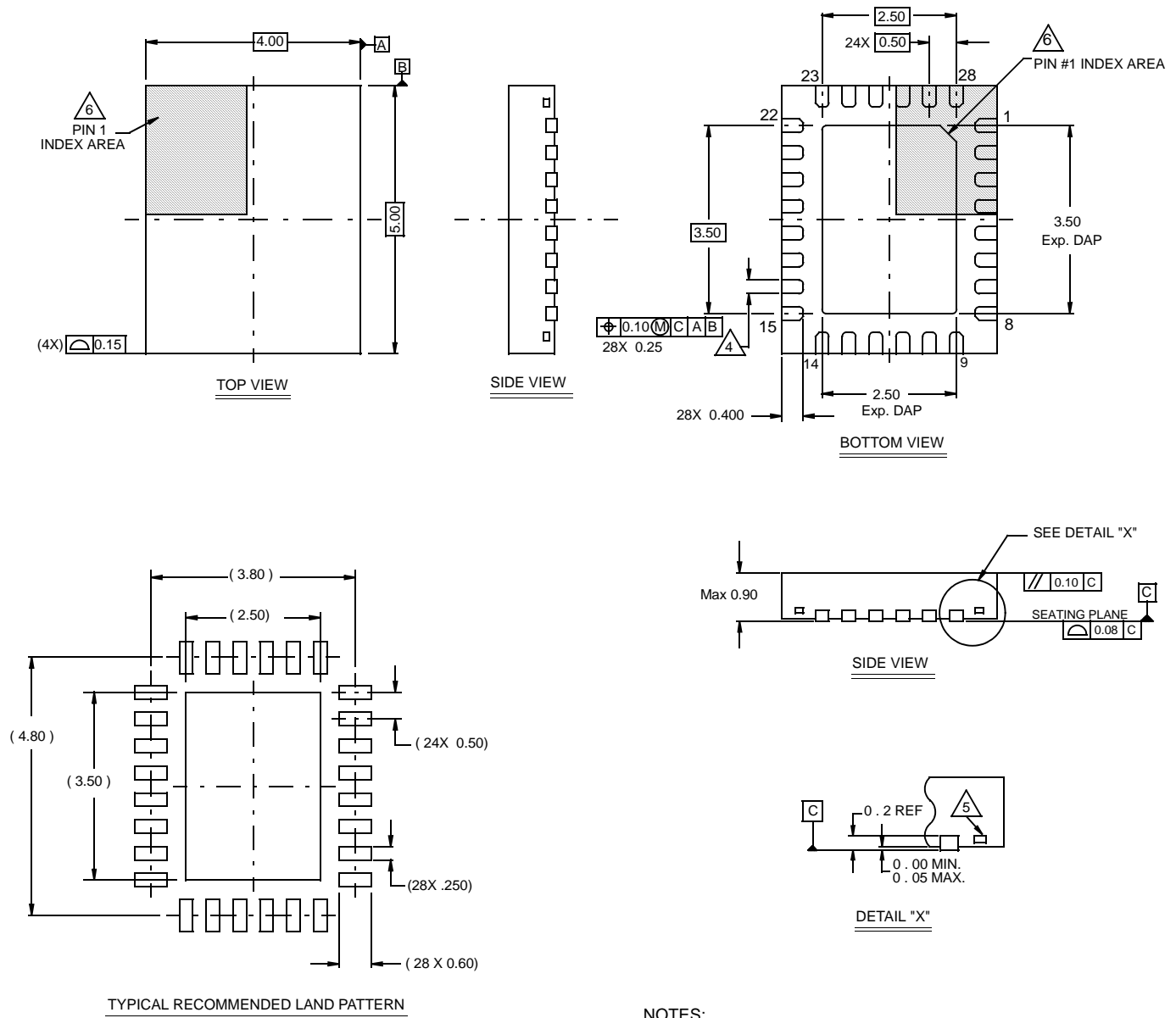
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Package Outline Drawing

L28.4x5A

28 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE

Rev 2, 06/08



NOTES:

1. Dimensions are in millimeters.
Dimensions in () for Reference Only.
2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
3. Unless otherwise specified, tolerance : Decimal ± 0.05
4. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
5. Tiebar shown (if present) is a non-functional feature.
6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.